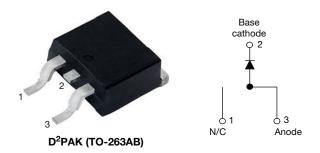
VS-6TQ035S-M3, VS-6TQ040S-M3, VS-6TQ045S-M3

Vishay Semiconductors

High Performance Schottky Rectifier, 6 A



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| PRIMARY CHARACTERISTICS | | | | | |
|----------------------------------|-------------------------------|--|--|--|--|
| I _{F(AV)} 6 A | | | | | |
| V _R | 35 V, 40 V, 45 V | | | | |
| V _F at I _F | 0.53 V | | | | |
| I _{RM} | 7 mA at 125 °C | | | | |
| T _J max. | 175 °C | | | | |
| E _{AS} | 8 mJ | | | | |
| Package | D ² PAK (TO-263AB) | | | | |
| Circuit configuration | Single | | | | |

FEATURES

- 175 °C T_J operation
- · High frequency operation
- Low forward voltage drop
- high High purity, temperature ероху encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-6TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | | |
|------------------------------------|---|-------------|----|--|--|--|--|--|
| SYMBOL CHARACTERISTICS VALUES UNIT | | | | | | | | |
| I _{F(AV)} | Rectangular waveform | 6 | А | | | | | |
| V _{RRM} | Range | 35 to 45 | V | | | | | |
| I _{FSM} | t _p = 5 μs sine | 690 | А | | | | | |
| VF | 6 A _{pk} , T _J = 125 °C | 0.53 | V | | | | | |
| TJ | Range | -55 to +175 | °C | | | | | |

| VOLTAGE RATINGS | | | | | | | | |
|--------------------------------------|------------------|---------------|---------------|---------------|-------|--|--|--|
| PARAMETER | SYMBOL | VS-6TQ035S-M3 | VS-6TQ040S-M3 | VS-6TQ045S-M3 | UNITS | | | |
| Maximum DC reverse voltage | V _R | 35 | 40 | 45 | V | | | |
| Maximum working peak reverse voltage | V _{RWM} | | 40 | 40 | v | | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | | |
|---|--------------------|---|--------|--------|-------|--|--|--|--|
| PARAMETER | SYMBOL | TEST COND | ITIONS | VALUES | UNITS | | | | |
| Maximum average forward current See fig. 5 | I _{F(AV)} | 50 % duty cycle at T_{C} = 164 °C | 6 | | | | | | |
| Maximum peak one cycle | | 5 μs sine or 3 μs rect. pulse Following any rated load 10 ms sine or 6 ms rect. pulse condition and with rated V _{RRM} applied | | 690 | А | | | | |
| non-repetitive surge current See fig. 7 | I _{FSM} | | | 140 | | | | | |
| Non-repetitive avalanche energy | E _{AS} | T _J = 25 °C, I _{AS} = 1.20 A, L = 11.10 mH | | 8 | mJ | | | | |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical | | 1.20 | А | | | | |

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VS-6TQ035S-M3, VS-6TQ040S-M3, VS-6TQ045S-M3



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| ELECTRICAL SPECIFICATIONS | | | | | |
|---------------------------------|--------------------------------|--|-------------------------|--------|-------|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | VALUES | UNITS |
| | | 6 A | T.I = 25 °C | 0.60 | V |
| Maximum forward voltage drop | V _{FM} ⁽¹⁾ | 12 A | 1j=25 C | 0.73 | |
| See fig. 1 | VFM (" | 6 A | T ₁ = 125 °C | 0.53 | |
| | | 12 A | 1j = 125 C | 0.64 | |
| Maximum reverse leakage current | I _{BM} ⁽¹⁾ | T _J = 25 °C | | 0.8 | mA |
| See fig. 2 | IRM \'' | T _J = 125 °C | $V_R = Rated V_R$ | 7 | |
| Threshold voltage | V _{F(TO)} | | | 0.35 | V |
| Forward slope resistance | r _t | $i_{j} = i_{j} maximum$ | $T_J = T_J maximum$ | | mΩ |
| Maximum junction capacitance | CT | V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz), 25 °C | | 400 | pF |
| Typical series inductance | L _S | Measured lead to lead 5 n | 8.0 | nH | |
| Maximum voltage rate of change | dV/dt | Rated V _R | | 10 000 | V/µs |

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 $\,\%$

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | |
|--|----------------|-----------------------------------|--|------------|------------|--|--|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | |
| Maximum junction and storage temperature range | | T _J , T _{Stg} | | -55 to 175 | °C | | | |
| Maximum thermal resistance, junction to case | | R _{thJC} | DC operation See fig. 4 | 2.2 | °C/W | | | |
| Typical thermal resistance, case to heatsink | | R _{thCS} | Mounting surface, smooth, and greased | 0.50 | 0/11 | | | |
| Approximate weight | | | | 2 | g | | | |
| Approximate weight | | | | 0.07 | oz. | | | |
| Mounting torque | minimum | | | 6 (5) | kgf∙cm | | | |
| Mounting torque maximum | | | | 12 (10) | (lbf · in) | | | |
| | Marking device | | | 6TQ035S | | | | |
| Marking device | | | Case style D ² PAK (TO-263AB) | 6TQ | 040S | | | |
| | | | | 6TQ0 | 045S | | | |

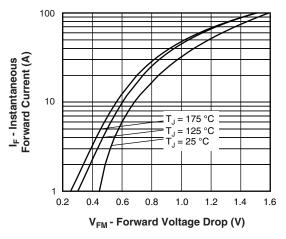
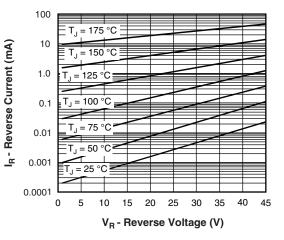
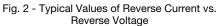


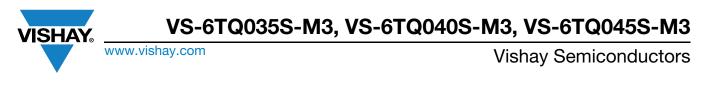
Fig. 1 - Maximum Forward Voltage Drop Characteristics





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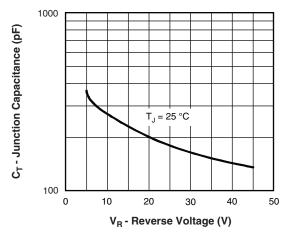


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

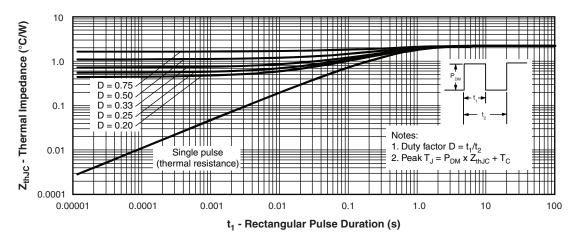


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Average Power Loss (W)

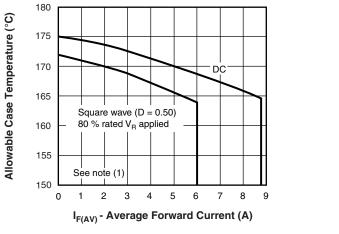


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

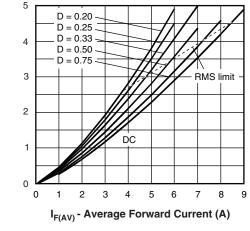


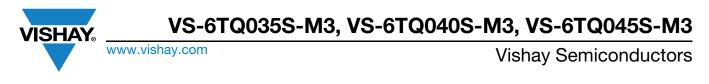
Fig. 6 - Forward Power Loss Characteristics

Revision: 21-Dec-2021

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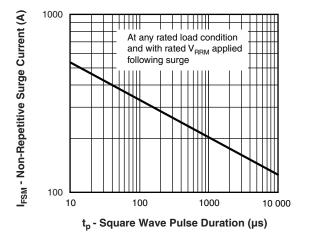


Fig. 7 - Maximum Non-Repetitive Surge Current

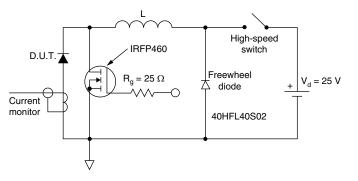


Fig. 8 - Unclamped Inductive Test Circuit

Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
 - $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

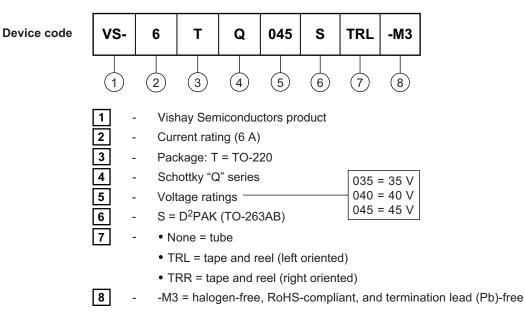
VS-6TQ035S-M3, VS-6TQ040S-M3, VS-6TQ045S-M3

Vishay Semiconductors

ORDERING INFORMATION TABLE

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| ORDERING INFORMATION | | | | | | | |
|----------------------|---------------|------------------------------------|--|--|--|--|--|
| PREFERRED P/N | BASE QUANTITY | PACKAGING DESCRIPTION | | | | | |
| VS-6TQ035S-M3 | 50 | Antistatic plastic tubes | | | | | |
| VS-6TQ035STRL-M3 | 800 | 13" diameter plastic tape and reel | | | | | |
| VS-6TQ035STRR-M3 | 800 | 13" diameter plastic tape and reel | | | | | |
| VS-6TQ040S-M3 | 50 | Antistatic plastic tubes | | | | | |
| VS-6TQ040STRL-M3 | 800 | 13" diameter plastic tape and reel | | | | | |
| VS-6TQ040STRR-M3 | 800 | 13" diameter plastic tape and reel | | | | | |
| VS-6TQ045S-M3 | 50 | Antistatic plastic tubes | | | | | |
| VS-6TQ045STRL-M3 | 800 | 13" diameter plastic tape and reel | | | | | |
| VS-6TQ045STRR-M3 | 800 | 13" diameter plastic tape and reel | | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | | |
|----------------------------|--------------------------|--|--|--|--|--|
| Dimensions | www.vishay.com/doc?96164 | | | | | |
| Part marking information | www.vishay.com/doc?95444 | | | | | |
| Packaging information | www.vishay.com/doc?96424 | | | | | |

Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



| ota | ted | 90 | °C |
|----------|------|-------------|----|
| <u>S</u> | cale | <u>ə:</u> 8 | :1 |

| SYMBOL | MILLIMETERS | | S INCHES | | NOTES | |
|--------|-------------|-------|----------|-------|-------|--|
| STMBOL | MIN. | MAX. | MIN. | MAX. | NOTES | |
| Α | 4.06 | 4.83 | 0.160 | 0.190 | | |
| A1 | 0.00 | 0.254 | 0.000 | 0.010 | | |
| b | 0.51 | 0.99 | 0.020 | 0.039 | | |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 | |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | |
| с | 0.38 | 0.74 | 0.015 | 0.029 | | |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 | |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 | |

| SYMBOL | MILLIM | ETERS | INC | HES | NOTES |
|--------|----------|-------|-----------|-------|-------|
| STNDUL | MIN. | MAX. | MIN. | MAX. | NOTES |
| D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| E | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| е | 2.54 BSC | | 0.100 BSC | | |
| Н | 14.61 | 15.88 | 0.575 | 0.625 | |
| L | 1.78 | 2.79 | 0.070 | 0.110 | |
| L1 | - | 1.65 | - | 0.066 | 3 |
| L2 | 1.27 | 1.78 | 0.050 | 0.070 | |
| L3 | 0.25 BSC | | 0.010 | BSC | |
| L4 | 4.78 | 5.28 | 0.188 | 0.208 | |

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 13-Jul-17

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Document Number: 96164

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